

U.S. UTILITY Patent Application

<p>O.I.P.E.</p> <p>SCANNED <i>AC 2</i> Q.A. <i>AA</i></p>	<p>PATENT DATE</p>
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APPLICATION NO.	CONT/PRIOR	CLASS	SUBCLASS	ART. UNIT	EXAMINER
09/930847	F	257	66	2811	hewitt

APPLICANTS: Po-Sheng Shih

TITLE: Method of manufacturing thin film transistor

PTO-204
12/99

[illegible]

<input type="checkbox"/> TERMINAL DISCLAIMER	DRAWINGS			CLAIMS ALLOWED	
	Sheets Dwg.	Figs. Dwg.	Print Fig.	Total Claims	Print Claim for O.G.
<input type="checkbox"/> The term of this patent subsequent to _____ (date) has been disclaimed. <input type="checkbox"/> The term of this patent shall not extend beyond the expiration date of U.S Patent. No. _____ _____ _____	_____ (Assistant Examiner) _____ (Date) _____ (Primary Examiner) _____ (Date) _____ (Legal Instruments Examiner) _____ (Date)			NOTICE OF ALLOWANCE MAILED	
				ISSUE FEE	
<input type="checkbox"/> The terminal _____ months of this patent have been disclaimed.				ISSUE BATCH NUMBER	

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